## **General Description**

The MAX4530/MAX4531/MAX4532 are low-voltage, CMOS analog ICs configured as an 8-channel multiplexer (mux) (MAX4530), two 4-channel muxes (MAX4531), and three single-pole/double-throw switches (MAX4532). These devices are pin compatible with the industry-standard 74HC4351/74HC4352/ 74HC4353. All devices have two complementary switch-enable inputs and address latching.

The MAX4530/MAX4531/MAX4532 operate from a single supply of +2V to +12V, or from dual supplies of ±2V to ±6V. On-resistance (150 $\Omega$  max) is matched between switches to 8 $\Omega$  max. Each switch can handle rail-to-rail analog signals. Off-leakage current is only 1nA at T<sub>A</sub> = +25°C and 50nA at T<sub>A</sub> = +85°C.

All digital inputs have 0.8V and 2.4V logic thresholds, ensuring both TTL- and CMOS-logic compatibility when using  $\pm 5V$  or a single  $\pm 5V$  supply.

#### **Applications**

Battery-Operated Equipment Data Acquisition Test Equipment Avionics Networking ATE Equipment Audio-Signal Routing

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

#### Pin Compatible with 74HC4351/74HC4352/74HC4353

- ±2.0V to ±6V Dual Supplies
   +2.0V to +12V Single Supply
- 75Ω Signal Paths with ±5V Supplies
   150Ω Signal Paths with +5V Supply
- ♦ Rail-to-Rail<sup>®</sup> Signal Handling
- ton and toff = 150ns and 120ns at ±4.5V
- ♦ <1µW Power Consumption</p>
- >2kV ESD Protection per Method 3015.7
- TTL/CMOS-Compatible Inputs
- Small, 20-Pin SSOP/SO/DIP Packages

#### **\_Ordering Information**

M/X/M

**Features** 

PART	TEMP. RANGE	PIN-PACKAGE
MAX4530CPP	0°C to +70°C	20 Plastic DIP
MAX4530CWP	0°C to +70°C	20 SO
MAX4530CAP	0°C to +70°C	20 SSOP
MAX4530C/D	0°C to +70°C	Dice*

Ordering Information continued at end of data sheet. \*Contact factory for availability.

#### **Pin Configurations**



#### MIXXIM

Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

### **ABSOLUTE MAXIMUM RATINGS**

Voltages Referenced to V- V+0.3 to +13V Voltage into Any Terminal (Note 1) 0.3 to (V+ + 0.3V) or ±20mA (whichever occurs first) Continuous Current into Any Terminal±20mA Peak Current, NO, NC, or COM_	Continuous Power Dissipation (T <sub>A</sub> = +70°C) 20-Pin Plastic DIP (derate 11.11mW/°C above +70°C)
(pulsed at 1ms, 10% duty cycle)±40mA ESD per Method 3015.7>2000V	MAX453_C_P0°C to +70°C MAX453_E_P40°C to +85°C
	Storage Temperature Range65°C to +150°C

Note 1: Voltages exceeding V+ or V- on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS—Dual Supplies**

(V+ = +5V ±10%, V- = -5V ±10%, GND = 0, VADD\_H = VEN\_H =  $V_{\overline{LE}}$  = 2.4V, VADD\_L = VEN\_L = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS
SWITCH	1							
Analog-Signal Range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub> _	(Note 3)			V-		V+	V
Channel On-Resistance	Ron	$I_{NO} = 2mA, V_{COM} =$	±3.5V,	$T_A = +25^{\circ}C$		45	75	Ω
Channel On-nesistance	NON	V + = +4.5V, V - = -4.8	ōV	$T_A = T_{MIN}$ to $T_{MAX}$			100	52
On-Resistance Matching	ΔRon	$I_{NO} = 2mA, V_{COM} =$	- ,	$T_A = +25^{\circ}C$		1	8	Ω
Between Channels (Note 4)	ANON	V + = +4.5V, V - = -4.8	ōV	$T_A = T_{MIN}$ to $T_{MAX}$			12	32
On-Resistance Flatness	R <sub>FLAT</sub> (ON)	$I_{NO} = 2mA; V_{COM} = -3$	$I_{NO} = 2mA; V_{COM} = -3V, 0V, +3V;$ V+ = 5V; V- = -5V			4	10	Ω
(Note 5)	TIFLAT(ON)	V+ = 5V; V- = -5V					13	52
NO-Off Leakage Current		110 - 7 0011	$V_{\rm NO} = \pm 4.5 V, V_{\rm COM} = 4.5 V, T_{\rm A} = +25^{\circ} C$	$T_A = +25^{\circ}C$	-1	0.01	1	nA
(Note 6)	I <sub>NO(OFF)</sub>	V+ = 5.5V, V- = -5.5V	/	$T_A = T_{MIN}$ to $T_{MAX}$	-10		10	
		$V_{COM} = \pm 4.5V,$ $V_{NO} = \pm 4.5V,$	MAX4530	$T_A = +25^{\circ}C$	-2	0.01	2	
COM-Off Leakage Current	ICOM(OFF)	V+ = 5.5V, V- = -5.5V		$T_A = T_{MIN}$ to $T_{MAX}$	-100		100	nA
(Note 6)		$V_{COM} = \pm 4.5V,$ $V_{NO} = \pm 4.5V,$	MAX4531/		-1	0.01	1	
		$V_{+} = 5.5V, V_{-} = -5.5V$			-50		50	
		$V_{COM} = \pm 4.5 V_{,}$	MAX4530	$T_A = +25^{\circ}C$	-2	0.01	2	
COM-On Leakage Current	ICOM(ON)	V + = 5.5V,	101/004000	$T_A = T_{MIN}$ to $T_{MAX}$	-100		100	nA
(Note 6)		V- = -5.5V	MAX4531/	$T_A = +25^{\circ}C$	-1	0.01	1	
			MAX4532	$T_A = T_{MIN}$ to $T_{MAX}$	-50		50	

## ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

 $(V_{+} = +5V \pm 10\%, V_{-} = -5V \pm 10\%, GND = 0, V_{ADD_H} = V_{EN_H} = V_{\overline{LE}} = 2.4V, V_{ADD_L} = V_{EN_L} = 0.8V, T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITION	IS	MIN	TYP (Note 2)	МАХ	UNITS
DIGITAL LOGIC INPUT							
Logic High Threshold	V <sub>ADD_H</sub> , V <sub>EN_H</sub> , V <u>LE</u>		$T_A = T_{MIN}$ to $T_{MAX}$		1.5	2.4	V
Logic Low Threshold	V <sub>ADD_L</sub> , V <sub>EN_L</sub> , V <u>LE</u>		$T_A = T_{MIN}$ to $T_{MAX}$	0.8	1.5		V
Input Current with Input Voltage High	IADD_H, IEN_H, ITE	V <sub>ADD_H</sub> = 2.4V, V <sub>ADD_L</sub> = 0.8V		-0.1	0.01	0.1	μA
Input Current with Input Voltage Low	I <sub>ADD_L</sub> , I <sub>EN_L</sub> , I <u>TE</u>	V <sub>ADD_H</sub> = 2.4V, V <sub>ADD_L</sub> = 0.8V		-0.1		0.1	μA
SUPPLY		-					
Power-Supply Range	V+, V-			±2.0		±6	V
Positive Supply Current	l+	V <sub>EN</sub> = V <sub>ADD</sub> = V <sub>LE</sub> = 0V/V+, V+ = 5.5V, V- = -5.5V	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$	-1 -10	0.001	1 10	μA
Negative Supply Current	-	$V_{EN_{-}} = V_{ADD_{-}} = V_{\overline{LE}} = 0V/V+,$ V+ = 5.5V, V- = -5.5V	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$	-1 -10	0.001	1 10	- μΑ
IGND Supply Current	I <sub>GND</sub>	V <sub>EN_</sub> = V <sub>ADD_</sub> = V <sub>LE</sub> = 0V/V+, V+ = 5.5V, V- = -5.5V	$T_{A} = +25^{\circ}C$ $T_{A} = T_{MIN} \text{ to } T_{MAX}$	-1 -10		1 10	μA
DYNAMIC				10		10	
Transition Time	<b>t</b> TRANS	Figure 1	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$		60	150 250	ns
Break-Before-Make Interval	tBBM	Figure 3	$T_A = +25^{\circ}C$	4	10	230	ns
Enable Turn-On Time	t <sub>ON(EN)</sub>	Figure 2	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$		10	150 250	– ns
Enable Turn-Off Time	toff(en)	Figure 2	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$		40	100 150	ns
Setup Time, Channel Select to Latch Enable	ts	Figure 4	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$	50 60			– ns
Hold Time, Latch Enable to Channel Select	t <sub>H</sub>	Figure 6	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$	0			– ns
Pulse Width, Latch Enable	t <sub>MPW</sub>	Figure 5	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$	60 70			- ns
Charge Injection (Note 3)	Q	$C_L = 1nF$ , $V_{NO} = 0V$ , Figure 6	$T_A = +25^{\circ}C$		1.5	5	рС
Off Isolation (Note 7)	VISO	$V_{EN2} = 0V, R_L = 1k\Omega,$ f = 1MHz	T <sub>A</sub> = +25°C		-65		dB
Crosstalk Between Channels	V <sub>CT</sub>	$\label{eq:VEN2} \begin{split} & V\overline{\text{EN1}} = 0\text{V}, \text{V}_{\text{EN2}} = 2.4\text{V}, \\ & f = 1\text{MHz}, \text{V}_{\text{GEN}} = 1\text{V}_{\text{P}\text{-}\text{P}}, \\ & \text{R}_{\text{L}} = 1\text{k}\Omega \end{split}$	$T_A = +25^{\circ}C$		-92		dB

### **ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)**

(V+ = +5V ±10%, V- = -5V ±10%, GND = 0, V<sub>ADD\_H</sub> = V<sub>EN\_H</sub> = V<sub>LE</sub> = 2.4V, V<sub>ADD\_L</sub> = V<sub>EN\_L</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	C	ONDITIONS		MIN TYP MAX (Note 2)	UNITS
Distortion, Total Harmonic	THD			T <sub>A</sub> = +25°C	0.025	0/0
Logic Input Capacitance	C <sub>IN</sub>	f = 1MHz		T <sub>A</sub> = +25°C	3	
NO-Off Capacitance	C <sub>NO(OFF)</sub>	$f = 1MHz, V_{EN} = V_{CON}$	v = 0V	$T_A = +25^{\circ}C$	3	pF
		£ 10411-	MAX4530		15	
COM-Off Capacitance	CCOM(OFF)	f = 1MHz, $V_{FN2} = V_{COM} = 0V$	$MAX/631 + A = \pm 26\%$	9	pF	
			MAX4532		6	
		f = 1MHz. MAX4530			26	
COM-On Capacitance	CCOM(ON)	VEN1 = VCOM = 0V,	MAX4531	T <sub>A</sub> = +25°C	20	pF
		$V_{EN2} = 2.4V$	MAX4532		17	

## ELECTRICAL CHARACTERISTICS—Single +5V Supply

 $(V + = +5V \pm 10\%, V - = 0, GND = 0, V_{ADD_H} = V_{EN_H} = V_{\overline{LE}} = 2.4V, V_{ADD_L} = V_{EN_L} = 0.8V, T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS
SWITCH	I	l		I.				
Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub>	(Note 3)			0		V+	V
On-Resistance	Ron	I <sub>NO</sub> = 1mA, V <sub>COM</sub> = 3	5V,	$T_A = +25^{\circ}C$		80	150	Ω
On-nesistance	NON	V + = 4.5V		$T_A = T_{MIN}$ to $T_{MAX}$			200	52
On-Resistance Matching Between	ΔRon	I <sub>NO</sub> = 1mA, V <sub>COM</sub> = 3.	5V,	$T_A = +25^{\circ}C$		2	15	Ω
Channels (Notes 3, 4)		V+ = 4.5V		$T_A = T_{MIN}$ to $T_{MAX}$			20	12
On-Resistance Flatness	R <sub>FLAT</sub>	I <sub>NO</sub> = 1mA; V <sub>COM</sub> = 3\ V+ = 5V	/, 2V, 1V;	$T_A = +25^{\circ}C$		10		Ω
NO-Off Leakage	hiology	$V_{NO} = 4.5V; V_{COM} = 4$	.5V, 1V;	$T_A = +25^{\circ}C$	-1		1	nA
Current (Note 8)	INO(OFF)	V+ = 5.5V		$T_A = T_{MIN}$ to $T_{MAX}$	-10		10	
			MAX4530	$T_A = +25^{\circ}C$	-2		2	
COM-Off Leakage		$V_{COM} = 4.5V, 1V;$ $V_{NO} = 1V, 4.5V;$	IVIAA4000	$T_A = T_{MIN}$ to $T_{MAX}$	-100		100	] nA
Current (Note 8)	ICOM(OFF)	$V_{\rm NO} = 10, 4.50,$ $V_{\rm +} = 5.5V$	MAX4531/	$T_A = +25^{\circ}C$	-1		1	
			MAX4532	$T_A = T_{MIN}$ to $T_{MAX}$	-50		50	
	MAX4530		$T_A = +25^{\circ}C$	-2		2		
COM-On Leakage				$T_A = T_{MIN}$ to $T_{MAX}$	-100		100	nA
Current (Note 8)	ICOM(ON)		MAX4531/	$T_A = +25^{\circ}C$	-1		1	
			MAX4532	$T_A = T_{MIN}$ to $T_{MAX}$	-50		50	

## ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

 $(V + = +5V \pm 10\%, V = 0, GND = 0, V_{ADD_H} = V_{EN_H} = V_{\overline{LE}} = 2.4V, V_{ADD_L} = V_{EN_L} = 0.8V, T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
DIGITAL LOGIC INPUT	I						
Logic-High Threshold	V <sub>ADD_H</sub> , V <sub>EN_H</sub> , V <sub>LE</sub>		$T_A = T_{MIN}$ to $T_{MAX}$		1.5	2.4	V
Logic-Low Threshold	V <sub>ADD_L</sub> , V <sub>EN_L</sub> , V <u>LE</u>		$T_A = T_{MIN}$ to $T_{MAX}$	0.8	1.5		V
Input Current with Input Voltage High	I <sub>ADD_H</sub> , I <sub>EN_H</sub> , I <u>LE</u>	$V_{H} = 2.4V, V_{L} = 0.8V$		-0.1		0.1	μA
Input Current with Input Voltage Low	I <sub>ADD_L</sub> , I <sub>EN_L</sub> , I <u>LE</u>	$V_{H} = 2.4V, V_{L} = 0.8V$		-0.1		0.1	μA
SUPPLY	1		I				
Power-Supply Range				2.0		12	V
Positive Supply Current	+	$V_{EN_} = V_{ADD} = V_{\overline{LE}} = 0V, V+;$	$T_A = +25^{\circ}C$	-1.0		1.0	
Positive Supply Current	1+	V + = 5.5V; V - = 0V	$T_A = T_{MIN}$ to $T_{MAX}$	-10		10	- μΑ
Negative Supply	-	$V_{EN} = V_{ADD} = V_{\overline{LE}} = 0V, V+;$	$T_A = +25^{\circ}C$	-1.0		1.0	- μΑ
Current	1-	V+ = 5.5V; V- = 0V	$T_A = T_{MIN}$ to $T_{MAX}$	-10		10	
IGND Supply Current		$V_{EN_} = V_{ADD} = V_{\overline{LE}} = 0V, V+;$	$T_A = +25^{\circ}C$	-1.0		1.0	μA
IGND Supply Current	IGND	V + = 5.5V; V - = 0V	$T_A = T_{MIN}$ to $T_{MAX}$	-10		10	] μΑ
DYNAMIC							
Transition Time	<b>t</b> TRANS	Figure 1, V <sub>NO</sub> = 3V	$T_A = +25^{\circ}C$		90	200	- ns
	URANS		$T_A = T_{MIN}$ to $T_{MAX}$			250	113
Break-Before-Make Interval	t <sub>BBM</sub>	Figure 3 (Note 3)	$T_A = +25^{\circ}C$	10	20		ns
Enable Turn-On Time		Figure 0	$T_A = +25^{\circ}C$		100	200	
(Note 3)	ton(en)	Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$			250	ns
Enable Turn-Off Time	torren	Figure 3	$T_A = +25^{\circ}C$		40	100	<b>n</b> 0
(Note 3)	toff(en)	Figure 3	$T_A = T_{MIN}$ to $T_{MAX}$			125	- ns
Set-Up Time, Channel	ts	Figure 7	$T_A = +25^{\circ}C$	50			ns
Select to Latch Enable	15		$T_A = T_{MIN}$ to $T_{MAX}$	60			110
Hold Time, Latch Enable	tH	Figure 7	$T_A = +25^{\circ}C$	0			- ns
to Channel Select	<u>п</u>		$T_A = T_{MIN}$ to $T_{MAX}$	0			115
Pulse Width, Latch	t <sub>MPW</sub>	Figure 7	$T_A = +25^{\circ}C$	60			ns
Enable			$T_A = T_{MIN}$ to $T_{MAX}$	70			
Charge Injection (Note 3)	Q	Figure 7, $C_L$ = 1nF, $V_{NO}$ = 0V	$T_A = +25^{\circ}C$		1.5	5	рС

### ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V+ = +5V \pm 10\%, V- = 0, GND = 0, V_{ADD_H} = V_{EN_H} = V_{\overline{LE}} = 2.4V, V_{ADD_L} = V_{EN_L} = 0.8V, T_A = T_{MIN}$  to T\_MAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH		•					
Analog Signal Range	Vanalog	(Note 3)		0		V+	V
On-Resistance	Rou	$I_{NO} = 1 mA, V_{COM} = 1.5V,$	$T_A = +25^{\circ}C$		220	500	Ω
On-nesistance	R <sub>ON</sub>	V + = 2.7V	$T_A = T_{MIN}$ to $T_{MAX}$			600	52
DYNAMIC		•					
Transition Time (Note 3)	t <sub>TRANS</sub>	Figure 1, $V_{IN} = 2.4V$ , $V_{NO1} = 1.5V$ , $V_{NO8} = 0V$	$T_A = +25^{\circ}C$		150	350	ns
Enable Turn-On Time (Note 3)	ton(en)	Figure 3, $V_{INH} = 2.4V$ , $V_{INL} = 0V$ , $V_{NO1} = 1.5V$	$T_A = +25^{\circ}C$		150	350	ns
Enable Turn-Off Time (Note 3)	tOFF(EN)	Figure 3, $V_{INH} = 2.4V$ , $V_{INL} = 0V$ , $V_{NO1} = 1.5V$	$T_A = +25^{\circ}C$		60	150	ns
Set-Up Time, Channel Select to Latch Enable)	ts	(Note 3)	$T_A = +25^{\circ}C$	100			ns
Hold Time, Latch Enable to Channel Select	tH	(Note 3)	$T_A = +25^{\circ}C$	0			ns
Pulse Width, Latch Enable	tMPW	(Note 3)	$T_A = +25^{\circ}C$	120			ns

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

**Note 4:**  $\Delta R_{ON} = R_{ON}(max) - R_{ON}(min)$ .

**Note 5:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges, i.e., V<sub>NO</sub> = 3V to 0V and 0V to -3V.

Note 6: Leakage parameters are 100% tested at maximum-rated hot-operating temperature, and guaranteed by correlation at  $T_A = +25^{\circ}C$ .

Note 7: Worst-case isolation is on channel 4 because of its proximity to the COM pin. Off isolation =  $20\log V_{COM} / V_{NO}$ ,  $V_{COM} = output$ ,  $V_{NO} = input$  to off switch.

Note 8: Leakage testing at single supply is guaranteed by correlation testing with dual supplies.

**Typical Operating Characteristics** 



 $(T_A = +25^{\circ}C, unless otherwise noted.)$ 

### **Pin Description**

	PIN		NAME	TUNISTICN
MAX4530	MAX4531	MAX4532	- NAME	FUNCTION
1, 2, 5, 6, 16, 17, 18, 19	_	_	NO0-NO7	Analog Switch Inputs 0-7
_	1, 2, 5, 6		NO0B-NO3B	Analog Switch "B" Inputs 0–3
_	_	1	NOB	Analog Switch "B" Normally Open Input
_	_	2	NCB	Analog Switch "B" Normally Closed Input
3, 14	3, 14	3, 14	N.C.	Not Internally Connected
4	—		COM	Analog Switch Common
_	4	19	COMB	Analog Switch "B" Common
_	_	4	NOA	Analog Switch "A" Normally Open Input
_	17	5	COMA	Analog Switch "A" Common
_	—	6	NCA	Analog Switch "A" Normally Closed Input
7	7	7	EN1	Enable Logic Input #1 (see Truth Table).
8	8	8	EN2	Enable Logic Input #2 (see Truth Table).
9	9	9	V-	Negative Analog Supply Voltage Input. Connect to GND for single supply operation.
10	10	10	GND	Negative Digital Supply Voltage Input. Connect to digital ground. (Analog signals have no ground
11	11	11	LE	Address Latch Logic Input (see Truth Table).
12	12	12	ADDA	Address "A" Logic Input (see Truth Table).
13	13	13	ADDB	Address "B" Logic Input (see Truth Table).
15	—	15	ADDC	Address "C" Logic Input (see Truth Table).
	15, 16, 18, 19		NO0A-NO3A	Analog Switch "A" Inputs 0–3
	_	16	NCC	Analog Switch "C" Normally Closed Input
_	—	17	NOC	Analog Switch "C" Normally Open Input
_	_	18	COMC	Analog Switch "C" Common
20	20	20	V+	Positive Analog and Digital Supply-Voltage Input

NO\_, NC\_, and COM\_ pins are identical and interchangeable. Either may be considered as an input or output; signals pass equally well in both directions.

## Applications Information

#### **Power-Supply Considerations**

Overview

The MAX4530/MAX4531/MAX4532 construction is typical of most CMOS analog switches. They have three supply pins: V+, V-, and GND. V+ and V- drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog-signal pin and both V+ and V-. One of these diodes conducts if any analog signal exceeds V+ or V-. During normal operation, these and other reverse-biased ESD diodes leak, forming the only current drawn from V+ or V-.

Virtually all of the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse-biased differently. Each is biased by either V+ or V- and the analog signal. This means their leakages vary as the signal varies. The difference in the two diode leakages to the V+ and Vpins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. For this reason, both sides of a given switch can show leakage currents of either the same or opposite polarity.

The analog-signal paths and GND are not connected.

V+ and GND power the internal logic and logic-level translators, and set both the input and output logic limits. The logic-level translators convert the logic levels into switched V+ and V- signals to drive the analog signals' gates. This drive signal is the only connection between the logic supplies and signals and the analog supplies. V+ and V- have ESD-protection diodes to GND.

The logic-level thresholds are TTL/CMOS compatible when V+ = +5V. As V+ rises, the threshold increases slightly, so when V+ reaches +12V, the threshold is about 3.1V—above the TTL guaranteed, high-level minimum of 2.8V, but still compatible with CMOS outputs.

#### **Bipolar Supplies**

The MAX4530/MAX4531/MAX4532 operate with bipolar supplies between  $\pm 2.0V$  and  $\pm 6V$ . The V+ and V- supplies need not be symmetrical, but their sum cannot exceed the  $\pm 13V$  absolute maximum rating.

#### Single Supply

The MAX4530/MAX4531/MAX4532 operate from a single supply between +2V and +12V when V- is connected to GND. All of the bipolar precautions must be observed. At room temperature, they actually work with a single supply at, near, or below +1.7V, although as supply voltage decreases, switch on-resistance and switching times become very high.

#### **High-Frequency Performance**

In 50 $\Omega$  systems, signal response is reasonably flat up to 50MHz (see *Typical Operating Characteristics*). Above 20MHz, the on response has several minor peaks that are highly layout-dependent. The problem is not in turning the switch on, but in turning it off. The offstate switch acts like a capacitor and passes higher frequencies with less attenuation. At 10MHz, off isolation is about -65dB in 50 $\Omega$  systems, becoming worse (approximately 20dB per decade) as frequency increases. Higher circuit impedances also make off isolation worse. Adjacent channel attenuation is about 3dB above that of a bare IC socket, and is due entirely to capacitive coupling.



**Test Circuits/Timing Diagrams** 

Figure 1. Address Transition Time



#### **Test Circuits/Timing Diagrams (continued)**

Figure 2. Enable Switching Time



**Test Circuits/Timing Diagrams (continued)** 



#### Test Circuits/Timing Diagrams (continued)

Figure 4. Charge Injection







Figure 6. NO/COM Capacitance



**Test Circuits/Timing Diagrams (continued)** 

Figure 7. Setup and Hold Times, Minimum LE Width

IE	EN2	EN1	AC	DRESS BI	TS		ON SWITCHES	
	ENZ	ENI	ADDC*	ADDB	ADDA	MAX4530	MAX4531	MAX4532
0	1	0	Х	Х	Х	Last address	Last address	Last address
Х	0	Х	Х	Х	Х	All switches open	All switches open	All switches open
Х	Х	1	Х	Х	Х	All switches open	All switches open	All switches open
1	1	0	0	0	0	COM-NO0	COMA–NO0A, COMB–NO0B	COMA–NCA, COMB–NCB, COMC–NCC
1	1	0	0	0	1	COM-NO1	COMA–NO1A, COMB–NO1B	COMA–NOA, COMB–NCB, COMC–NCC
1	1	0	0	1	0	COM-NO2	COMA–NO2A, COMB–NO2B	COMA–NCA, COMB–NOB, COMC–NCC
1	1	0	0	1	1	COM-NO3	COMA–NO3A, COMB–NO3B	COMA–NOA, COMB–NOB, COMC–NCC
1	1	0	1	0	0	COM-NO4	COMA-NO0A, COMB-NO0B	COMA–NCA, COMB–NCB, COMC–NOC
1	1	0	1	0	1	COM-NO5	COMA-NO1A, COMB-NO1B	COMA–NOA, COMB–NCB, COMC–NOC
1	1	0	1	1	0	COM-NO6	COMA–NO2A, COMB–NO2B	COMA–NCA, COMB–NOB, COMC–NOC
1	1	0	1	1	1	COM-NO7	COMA–NO3A, COMB–NO3B	COMA–NOA, COMB–NOB, COMC–NOC

### Truth Table/Switch Programming

X = Don't Care \*ADDC not present on MAX4531.

Note: NO\_ and COM\_ pins are identical and interchangeable. Either may be considered an input or an output; signals pass equally well in either direction. LE is independent of EN1 and EN2.

PART	TEMP. RANGE	PIN-PACKAGE
MAX4530EPP	-40°C to +85°C	20 Plastic DIP
MAX4530EWP	-40°C to +85°C	20 SO
MAX4530EAP	-40°C to +85°C	20 SSOP
MAX4531CPP	0°C to +70°C	20 Plastic DIP
MAX4531CWP	0°C to +70°C	20 SO
MAX4531CAP	0°C to +70°C	20 SSOP
MAX4531C/D	0°C to +70°C	Dice*
MAX4531EPP	-40°C to +85°C	20 Plastic DIP
MAX4531EWP	-40°C to +85°C	20 SO
MAX4531EAP	-40°C to +85°C	20 SSOP

#### **Ordering Information (continued)**

PART	TEMP. RANGE	PIN-PACKAGE
MAX4532CPP	0°C to +70°C	20 Plastic DIP
MAX4532CWP	0°C to +70°C	20 SO
MAX4532CAP	0°C to +70°C	20 SSOP
MAX4532C/D	0°C to +70°C	Dice*
MAX4532EPP	-40°C to +85°C	20 Plastic DIP
MAX4532EWP	-40°C to +85°C	20 SO
MAX4532EAP	-40°C to +85°C	20 SSOP

**Chip Topographies** 

0.081"

(2.06mm)

\* Contact factory for availability.



#### MAX4530/MAX4532



() ARE FOR MAX4532

TRANSISTOR COUNT: 255 SUBSTRATE CONNECTED TO V+

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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